NSN 5961-01-084-2584

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View Online at https://aerobasegroup.com/nsn/5961-01-084-2584 **Inclosure Material:** Metal **Overall Length:** 0.280 inches Overall Diameter: Between 0.300 inches and 0.370 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 collector to emitter reverse voltage, with base short-circuited to emitter and 33.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 5.8 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Burn-in requirement, vce 7.0vdc, ic 0.4adc, 168 hours min duration; junction pattern arrangement: npn **Test Data Document:** 99971-7536771 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: